

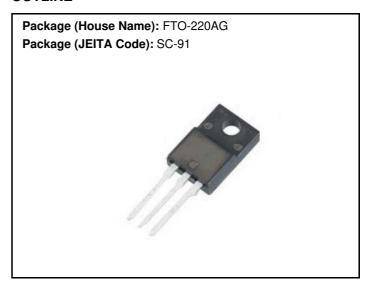
# P7F90VX3

# Power MOSFETs 900V, 7A, N-channel

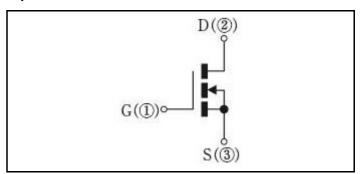
### **Feature**

- N-channel
- High Voltage (900V)
- · High ESD Capability
- · Low Capacitance
- High Avalanche Durability, High di/dt Durability
- Pb free terminal
- RoHS:Yes

### **OUTLINE**



## **Equivalent circuit**



# $\textbf{Absolute Maximum Ratings} \quad \text{(unless otherwise specified : } Tc=25\,^{\circ}C)$

| Item                              | Symbol          | Conditions                    | Ratings    | Unit |
|-----------------------------------|-----------------|-------------------------------|------------|------|
| Storage temperature               | Tstg            |                               | -55 to 150 | °C   |
| Channel tempertature              | Tch             |                               | -55 to 150 | °C   |
| Drain-source voltage              | $V_{DSS}$       |                               | 900        | V    |
| Gate-source voltage               | $V_{GSS}$       |                               | ±30        | V    |
| Continuous drain current(DC)      | I <sub>D</sub>  |                               | 7          | Α    |
| Continuous drain current(Peak)    | I <sub>DP</sub> | Pulse width 10µs, duty=1/100  | 21         | Α    |
| Continuous source current(DC)     | ls              |                               | 7          | Α    |
| Total power dissipation           | P <sub>T</sub>  |                               | 95         | W    |
| Repetitive avalanche current      | I <sub>AR</sub> | Starting Tch=25°C Tch≦150°C   | 7          | Α    |
| Single avalanche energy           | E <sub>AS</sub> | Starting Tch=25°C Tch≦150°C   | 80         | mJ   |
| Repetitive avalanche energy       | E <sub>AR</sub> | Starting Tch=25°C Tch≦150°C   | 8          | mJ   |
| Drain-source diode di/dt strength | di/dt           | Is=7A, Tc=25°C                | 350        | A/μs |
| Dielectric strenght               | Vdis            | Terminals to case, AC1min     | 2 kV       |      |
| Mounting torque                   | TOR             | (Recommended torque : 0.3N⋅m) | 0.5 N·n    |      |

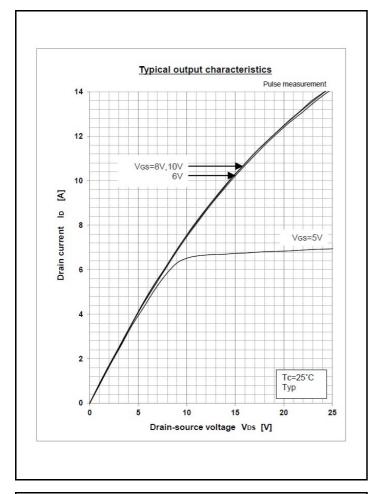
<sup>\* :</sup>See the original Specifications

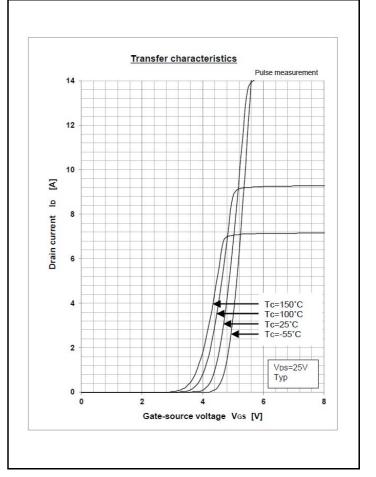
# **Electrical Characteristics** (unless otherwise specified : Tc=25°C)

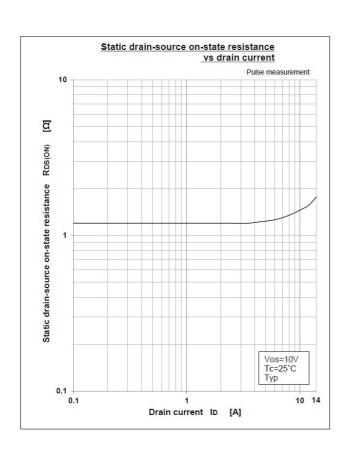
| Item                                    | Symbol              | Conditions   | Ratings |      |      | Unit |
|---|---------------------|--|---------|------|------|------|
|   |                     |  | MIN     | TYP  | MAX  | Unit |
| Drain-Source breakdown voltage          | $V_{(BR)DSS}$       | ID=1mA, VGS=0V   | 900     |      |      | V    |
| Zero gate voltage drain current         | I <sub>DSS</sub>    | VDS=900V, VGS=0V   |         |      | 100  | μΑ   |
| Gate-source leakage current             | I <sub>GSS</sub>    | VGS=±25V, VDS=0V   |         |      | ±10  | μΑ   |
| Forward transconductance                | 9 <sub>fs</sub>     | ID=3.5A, VDS=10V   | 4.3     | 9.9  |      | S    |
| Static drain-source on-state resistance | R <sub>DS(ON)</sub> | ID=3.5A, VGS=10V   |         | 1.2  | 1.7  | Ω    |
| Gate threshold voltage                  | Vth                 | ID=1mA, VDS=10V  | 3       |      | 4    | ٧    |
| Source-drain diode forward voltage      | $V_{SD}$            | IS=3.5A, VGS=0V  |         |      | 1.5  | V    |
| Thermal resistance                      | Rth(j-c)            | Junction to case, with heatsink  |         |      | 1.58 | °C/W |
| Total gate charge                       | Qg                  | VDD=400V, VGS=10V, ID=7A   |         | 42   |      | nC   |
| Input capacitance                       | Ciss                | VDS=50V, VGS=0V, f=1MHz  |         | 1375 |      | pF   |
| Reverce transfer capacitnce             | Crss                | VDS=50V, VGS=0V, f=1MHz  |         | 9.5  |      | pF   |
| Output capacitance                      | Coss                | VDS=50V, VGS=0V, f=1MHz  |         | 100  |      | pF   |
| Turn-on delay time                      | td(on)              | ID=3.5A, RL=43 $\Omega$ , VDD=150V, Rg=50 $\Omega$ , VGS(+)=10V, VGS(-)=0V |         | 48   |      | ns   |
| Rise time                               | tr                  | ID=3.5A, RL=43 $\Omega$ , VDD=150V, Rg=50 $\Omega$ , VGS(+)=10V, VGS(-)=0V |         | 67   |      | ns   |
| Turn-off delay time                     | td(off)             | ID=3.5A, RL=43 $\Omega$ , VDD=150V, Rg=50 $\Omega$ , VGS(+)=10V, VGS(-)=0V |         | 265  |      | ns   |
| Fall time                               | tf                  | ID=3.5A, RL=43 $\Omega$ , VDD=150V, Rg=50 $\Omega$ , VGS(+)=10V, VGS(-)=0V |         | 79   |      | ns   |

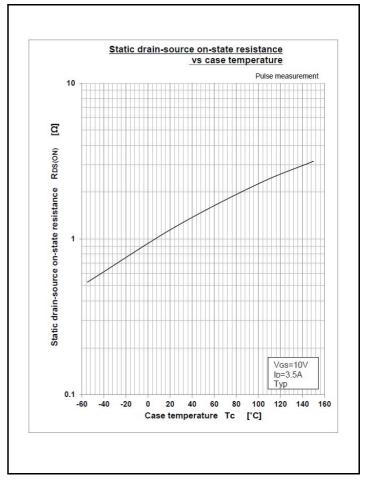
 $<sup>\</sup>ensuremath{\,*\,}$  :See the original Specifications

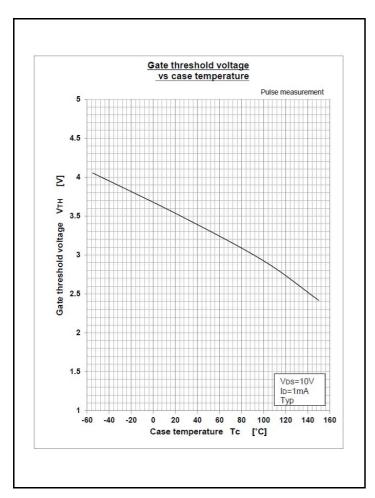
## **CHARACTERISTIC DIAGRAMS**

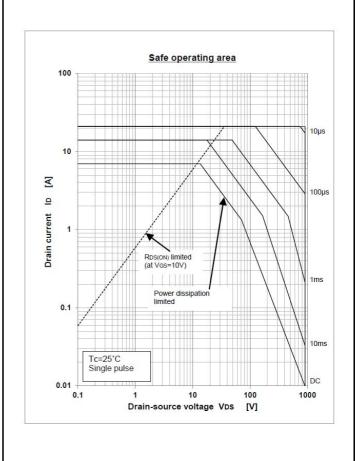


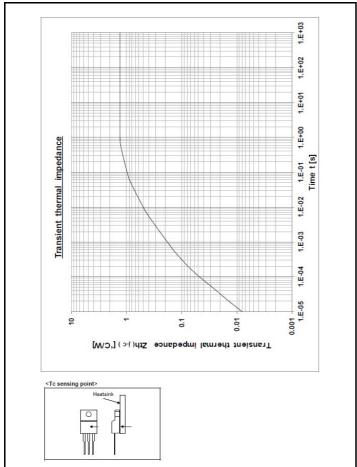


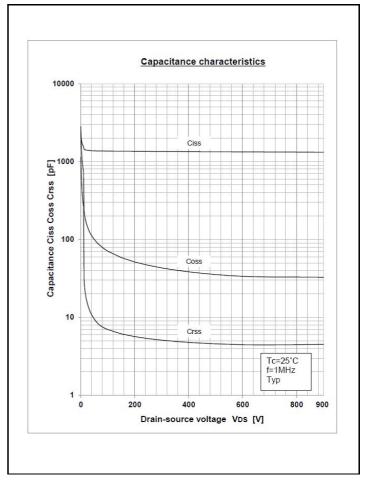


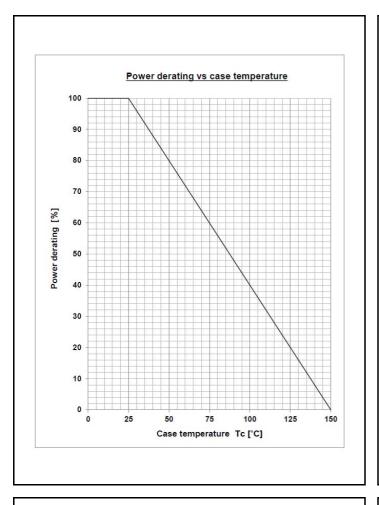


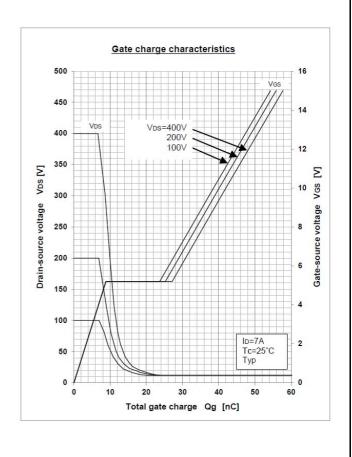


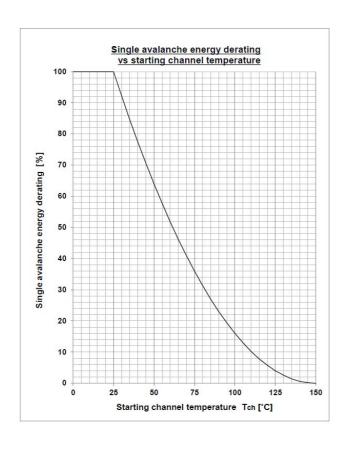


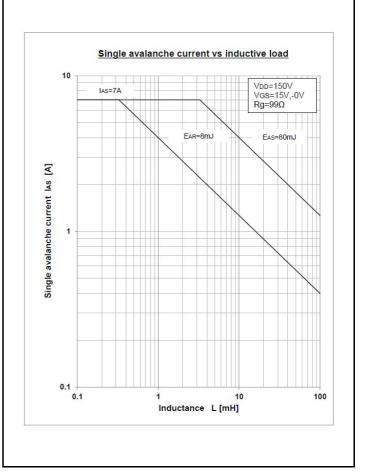










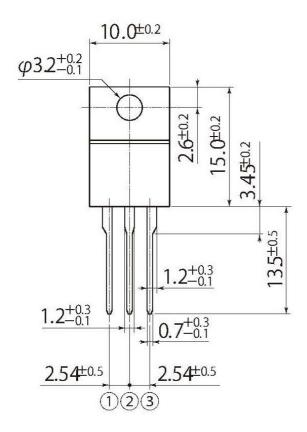


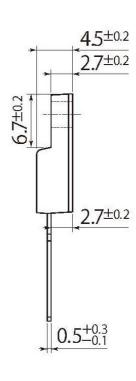
unit:mm

scale: 2/1

**J8** 

| JEDEC Code | -               |  |  |
|------------|-----------------|--|--|
| JEITA Code | SC-91           |  |  |
| House Name | FTO-220AG(3pin) |  |  |





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